

TPC8132

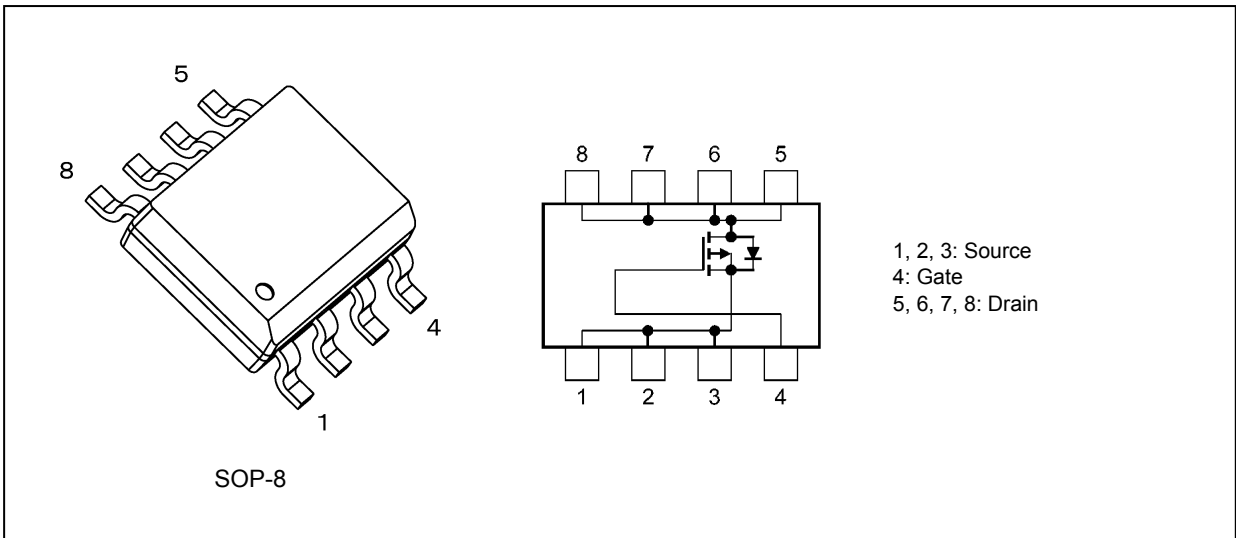
1. Applications

- Lithium-Ion Secondary Batteries
- Power Management Switches

2. Features

- (1) Small footprint due to small and thin package
- (2) Low drain-source on-resistance: $R_{DS(ON)} = 20 \text{ m}\Omega$ (typ.) ($V_{GS} = -10 \text{ V}$)
- (3) Low leakage current: $I_{DSS} = -10 \text{ }\mu\text{A}$ (max) ($V_{DS} = -40 \text{ V}$)
- (4) Enhancement mode: $V_{th} = -0.8$ to -2.0 V ($V_{DS} = -10 \text{ V}$, $I_D = -0.2 \text{ mA}$)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Rating | Unit |
|-------------------------------|---------------------------|------------|------------------|
| Drain-source voltage | V_{DSS} | -40 | V |
| Gate-source voltage | V_{GSS} | -25/+20 | |
| Drain current (DC) | (Note 1) I_D | -7 | A |
| Drain current (pulsed) | (Note 1) I_{DP} | -28 | |
| Power dissipation | (t = 10 s) (Note 2) P_D | 1.9 | W |
| Power dissipation | (t = 10 s) (Note 3) P_D | 1.0 | W |
| Single-pulse avalanche energy | (Note 4) E_{AS} | 22 | mJ |
| Avalanche current | I_{AR} | -7 | A |
| Channel temperature | T_{ch} | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to 150 | |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production

2010-11

5. Thermal Characteristics

| Characteristics | | | Symbol | Max | Unit |
|---------------------------------------|------------|----------|----------------|------|------|
| Channel-to-ambient thermal resistance | (t = 10 s) | (Note 2) | $R_{th(ch-a)}$ | 65.7 | °C/W |
| Channel-to-ambient thermal resistance | (t = 10 s) | (Note 3) | $R_{th(ch-a)}$ | 125 | °C/W |

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4: $V_{DD} = -24\text{ V}$, $T_{ch} = 25^\circ\text{C}$ (initial), $L = 0.5\text{ mH}$, $R_G = 25\ \Omega$, $I_{AR} = -7\text{ A}$



Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

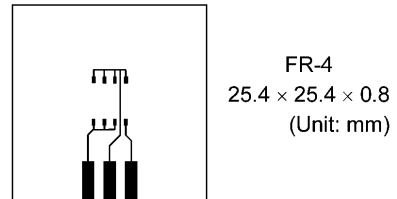


Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

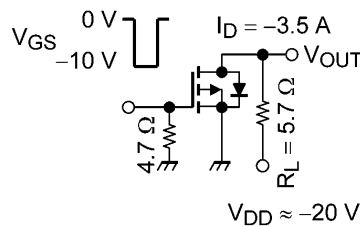
6.1. Static Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|---------------|---|------|------|-----------|------------------|
| Gate leakage current | I_{GSS} | $V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$ | — | — | ± 0.1 | μA |
| Drain cut-off current | I_{DSS} | $V_{DS} = -40\text{ V}, V_{GS} = 0\text{ V}$ | — | — | -10 | |
| Drain-source breakdown voltage | $V_{(BR)DSS}$ | $I_D = -10\text{ mA}, V_{GS} = 0\text{ V}$ | -40 | — | — | V |
| Drain-source breakdown voltage (Note 5) | $V_{(BR)DSX}$ | $I_D = -10\text{ mA}, V_{GS} = 10\text{ V}$ | -30 | — | — | |
| Gate threshold voltage | V_{th} | $V_{DS} = -10\text{ V}, I_D = -0.2\text{ mA}$ | -0.8 | — | -2.0 | |
| Drain-source on-resistance | $R_{DS(ON)}$ | $V_{GS} = -4.5\text{ V}, I_D = -3.5\text{ A}$ | — | 25 | 33 | $\text{m}\Omega$ |
| | | $V_{GS} = -10\text{ V}, I_D = -3.5\text{ A}$ | — | 20 | 25 | |

Note 5: If a forward bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|--------------------------------|-----------|--|-----|------|-----|------|
| Input capacitance | C_{iss} | $V_{DS} = -10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$ | — | 1580 | — | pF |
| Reverse transfer capacitance | C_{rss} | | — | 190 | — | |
| Output capacitance | C_{oss} | | — | 230 | — | |
| Switching time (rise time) | t_r | See Figure 6.2.1. | — | 8 | — | ns |
| Switching time (turn-on time) | t_{on} | | — | 16 | — | |
| Switching time (fall time) | t_f | | — | 46 | — | |
| Switching time (turn-off time) | t_{off} | | — | 180 | — | |



Duty $\leq 1\%$, $t_w = 10\ \mu\text{s}$

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|-----------|---|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | Q_g | $V_{DD} \approx -32\text{ V}, V_{GS} = -10\text{ V}, I_D = -7\text{ A}$ | — | 34 | — | nC |
| Gate-source charge 1 | Q_{gs1} | | — | 3.2 | — | |
| Gate-drain charge | Q_{gd} | | — | 8.8 | — | |

6.4. Source-Drain Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|-----------|---|-----|------|-----|------|
| Reverse drain current (pulsed) (Note 6) | I_{DRP} | — | — | — | -28 | A |
| Diode forward voltage | V_{DSF} | $I_{DR} = -7\text{ A}, V_{GS} = 0\text{ V}$ | — | — | 1.2 | V |

Note 6: Ensure that the channel temperature does not exceed 150°C .

7. Marking (Note)

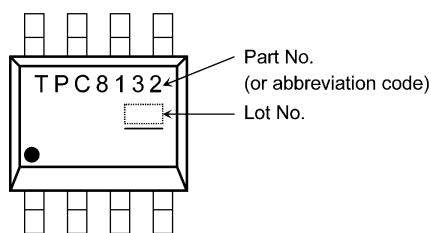


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.
 Not underlined: [[Pb]]/INCLUDES > MCV
 Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]
 Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.
 The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

8. Characteristics Curves (Note)

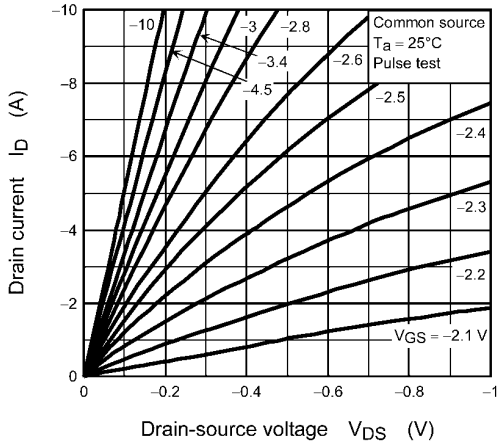


Fig. 8.1 $I_D - V_{DS}$

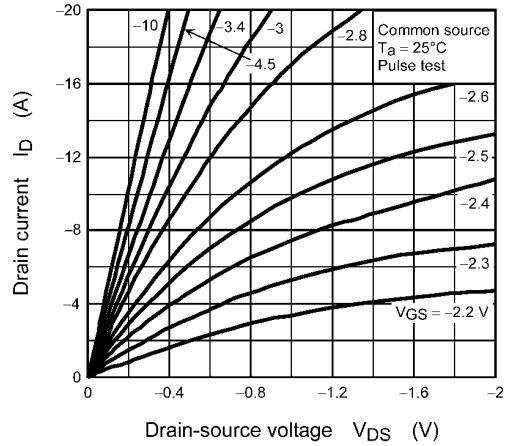


Fig. 8.2 $I_D - V_{DS}$

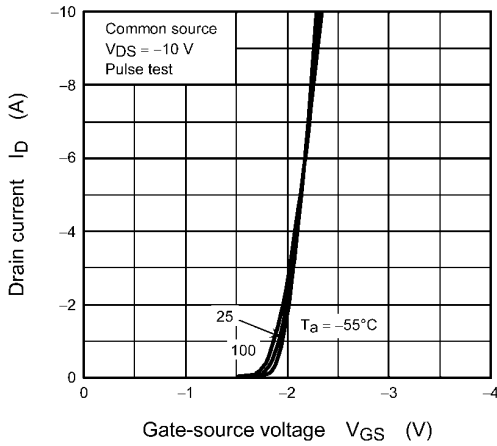


Fig. 8.3 $I_D - V_{GS}$

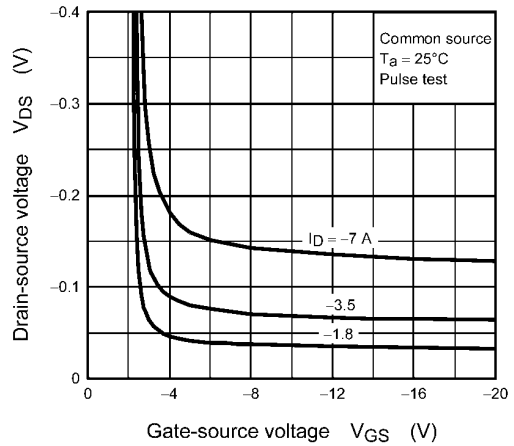


Fig. 8.4 $V_{DS} - V_{GS}$

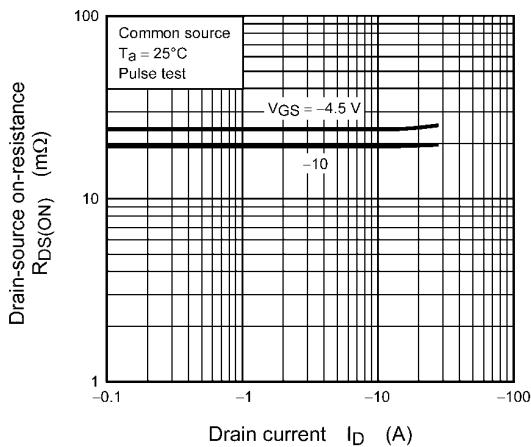


Fig. 8.5 $R_{DS(ON)} - I_D$

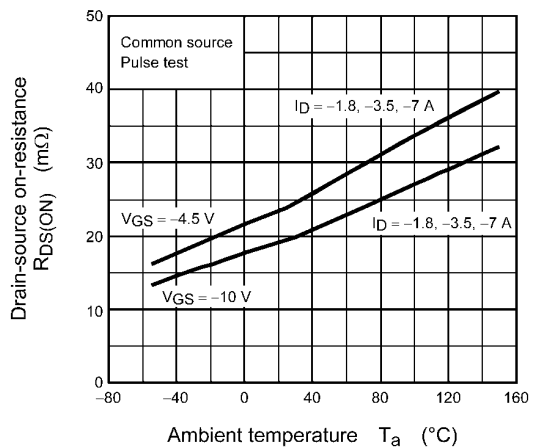


Fig. 8.6 $R_{DS(ON)} - T_a$

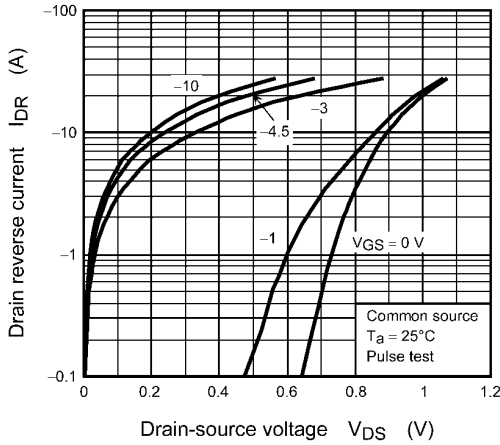


Fig. 8.7 $I_{DR} - V_{DS}$

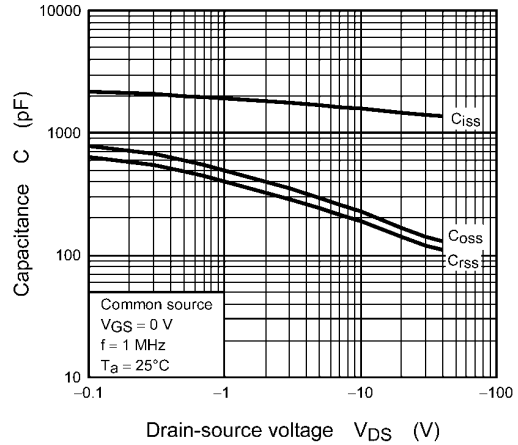


Fig. 8.8 Capacitance - V_{DS}

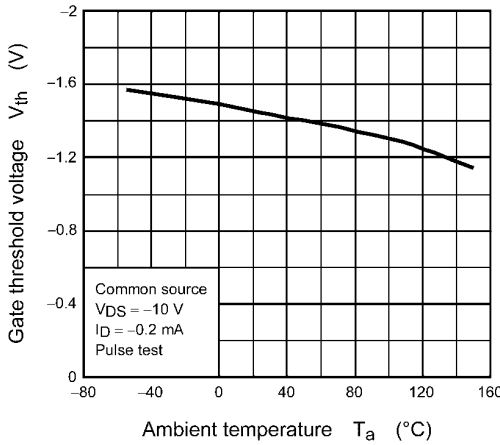


Fig. 8.9 $V_{th} - T_a$

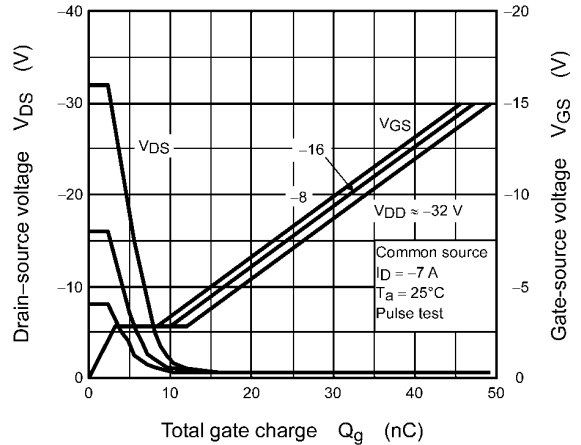
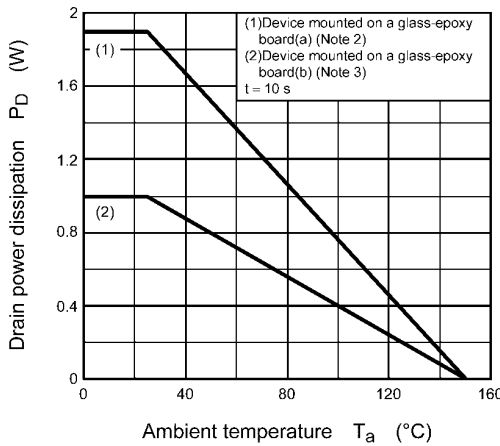


Fig. 8.10 Dynamic Input/Output Characteristics



**Fig. 8.11 $P_D - T_a$
(Guaranteed Maximum)**

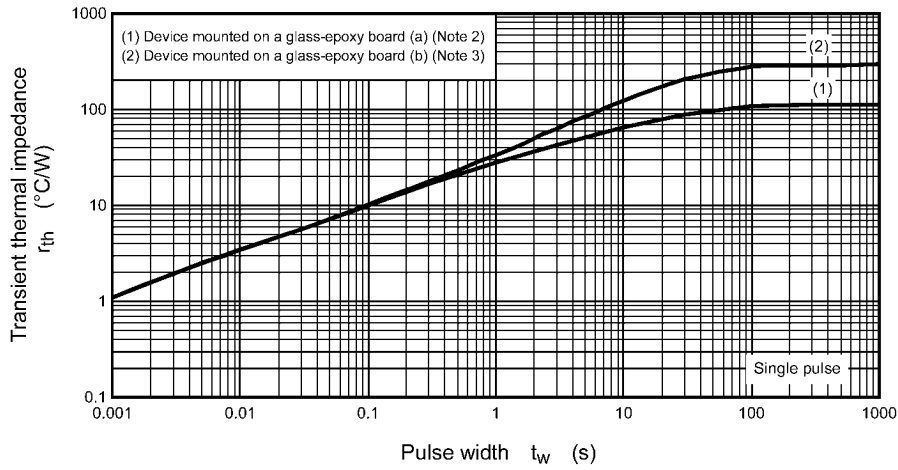


Fig. 8.12 $r_{th} - t_w$
(Guaranteed Maximum)

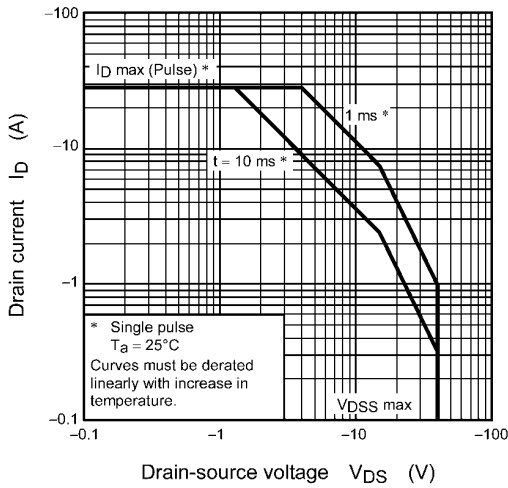
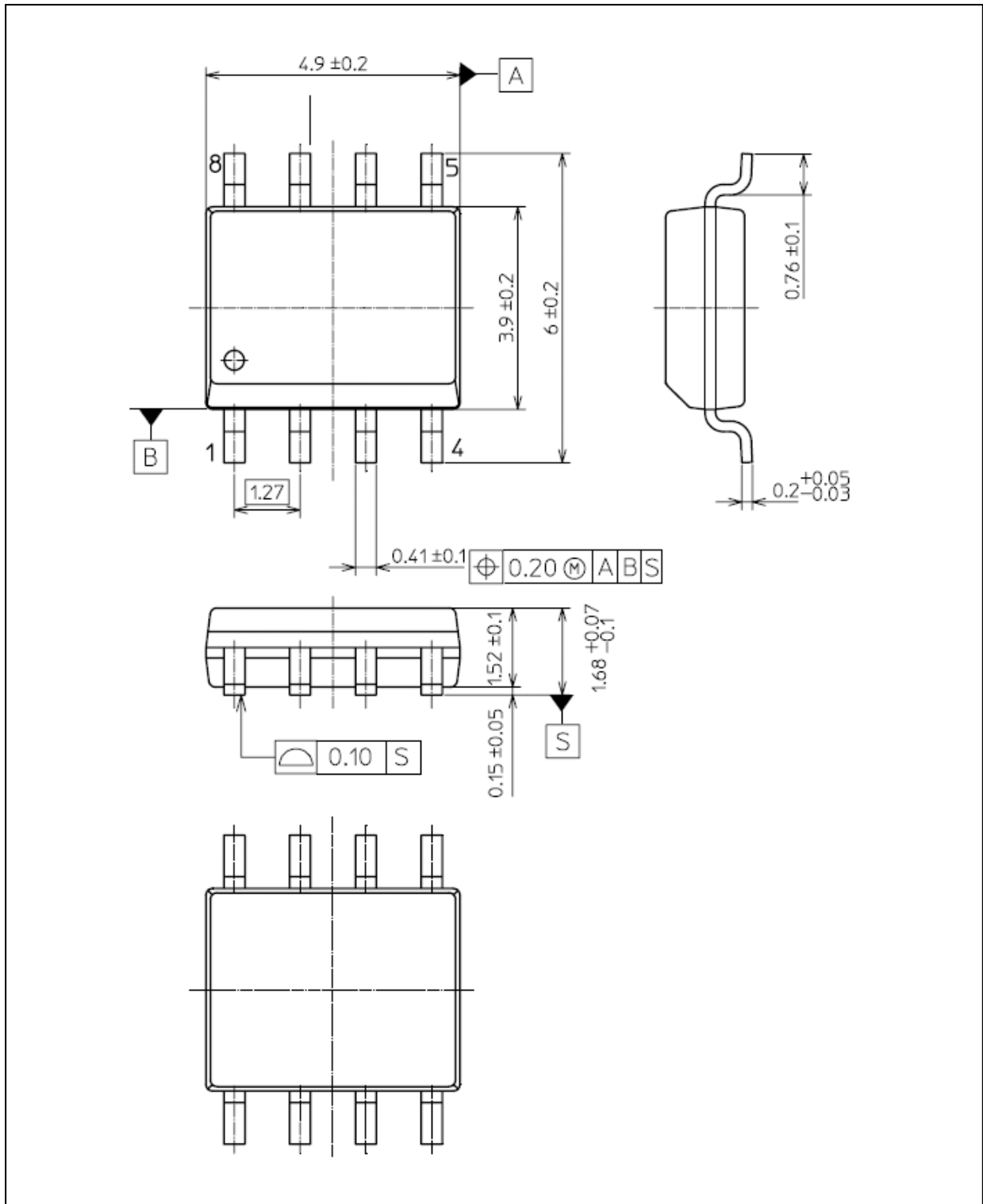


Fig. 8.13 Safe Operating Area
(Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 0.085 g (typ.)

| Package Name(s) |
|-----------------|
| TOSHIBA: 2-5R1S |
| Nickname: SOP-8 |

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